Amendments to the Claims:

Listing of Claims:

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1 (original): An extrusion-free wet cleaning process, comprising:

5 providing a wet cleaning tool;

preparing a wafer having a main surface comprising at least one exposed copper feature and a dielectric film;

transferring said wafer into said wet cleaning tool in a light inhibited manner; and cleaning said main surface of said wafer by contacting a cleaning solution in said light inhibited manner.

2 (original): The extrusion-free wet cleaning process according to claim 1 wherein said wafer is a semiconductor wafer.

15 3 (original): The extrusion-free wet cleaning process according to claim 1 wherein said exposed copper feature is damascened into said dielectric film.

4 (original): The extrusion-free wet cleaning process according to claim 1 wherein during said cleaning step of said main surface of said wafer in said light inhibited manner, said wafer is not exposed to light.

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5 (original): The extrusion-free wet cleaning process according to claim 1 wherein said wet cleaning tool comprises a succession of sinks containing said cleaning solution.

6 (original): The extrusion-free wet cleaning process according to claim 1 wherein said wet cleaning tool is a single-wafer cleaning tool.

7 (currently amended): A wafer wet cleaning system comprising a wet cleaning tool for performing a wafer cleaning process, a first light inhibiting means for transferring said wafer into said wet cleaning tool, and a second light inhibiting means for preventing a wafer to be cleaned from light exposure during said wafer cleaning process.

8 (original): The wafer wet cleaning system according to claim 7 wherein said wet cleaning tool comprises a succession of sinks for containing cleaning solution.

15 9 (original): The wafer wet cleaning system according to claim 7 wherein said wet cleaning tool is a single-wafer cleaning tool.

10 (original): The wafer wet cleaning system according to claim 7 wherein said wafer has a main surface comprising at least one exposed copper feature and a dielectric film.

11 (original): The extrusion free wet cleaning process according to claim 7 wherein said

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wafer is a semiconductor wafer.